NSN 5962-01-361-2766

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View Online at https://aerobasegroup.com/nsn/5962-01-361-2766

Body Length:
1.111 inches
Body Width:
Between 0.350 inches and 0.410 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
495.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and static operation
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
18 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-7 mil-m-38510
Current Rating Per Characteristic:
90.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
6.00 input picofarads and 7.00 output picofarads
Time Rating Per Chacteristic:
15.00 nanoseconds access
Memory Device Type:
Ram
Special Features:
Nuclear hardness critical item
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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